













6-Pin DIP Random-Phase Optoisolators Triac Driver Output (250 Volts Peak)

The MOC3010 Series consists of gallium arsenide infrared emitting diodes, optically coupled to silicon bilateral switch and are designed for applications requiring isolated triac triggering, low-current isolated ac switching, high electrical isolation (to 7500 Vac peak), high detector standoff voltage, small size, and low cost.

 To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.

Recommended for 115 Vac(rms) Applications:

- Solenoid/Valve Controls
- Lamp Ballasts
- Interfacing Microprocessors to 115 Vac Peripherals
- Motor Controls
- Static ac Power Switch
- Solid State Relays
- Incandescent Lamp Dimmers

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INFRARED EMITTING DIODE			
Reverse Voltage	٧R	3	Volts
Forward Current — Continuous	lF	60	mA
Total Power Dissipation @ T _A = 25°C Negligible Power in Transistor Derate above 25°C	PD	100 1.33	mW mW/°C

OUTPUT DRIVER

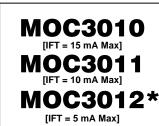
Off–State Output Terminal Voltage	VDRM	250	Volts
Peak Repetitive Surge Current (PW = 1 ms, 120 pps)	ITSM	1	Α
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	300 4	mW mW/°C

TOTAL DEVICE

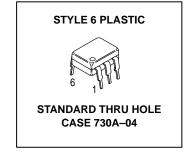
Isolation Surge Voltage ⁽¹⁾ (Peak ac Voltage, 60 Hz, 1 Second Duration)	VISO	7500	Vac(pk)
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	330 4.4	mW mW/°C
Junction Temperature Range	TJ	-40 to +100	°C
Ambient Operating Temperature Range(2)	TA	-40 to +85	°C
Storage Temperature Range(2)	T _{stg}	-40 to +150	°C
Soldering Temperature (10 s)	TL	260	°C

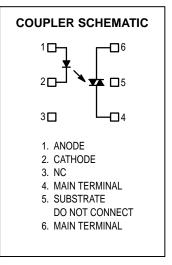
- Isolation surge voltage, V_{ISO}, is an internal device dielectric breakdown rating.
 For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.
- 2. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions. **Preferred** devices are Motorola recommended choices for future use and best overall value. GlobalOptoisolator is a trademark of Motorola, Inc.

(Replaces MOC3009/D)



*Motorola Preferred Device







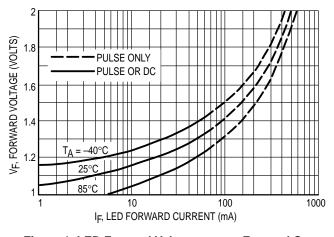
MOC3010 MOC3011 MOC3012

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
NPUT LED	•	•			•
Reverse Leakage Current (V _R = 3 V)	I _R	_	0.05	100	μА
Forward Voltage (IF = 10 mA)	VF	_	1.15	1.5	Volts
OUTPUT DETECTOR (I _F = 0 unless otherwise noted)	•	•			•
Peak Blocking Current, Either Direction (Rated V _{DRM} ⁽¹⁾)	IDRM	_	10	100	nA
Peak On–State Voltage, Either Direction (I _{TM} = 100 mA Peak)	VTM	_	1.8	3	Volts
Critical Rate of Rise of Off–State Voltage (Figure 7, Note 2)	dv/dt	_	10	_	V/μs
COUPLED	•	•	•		•
LED Trigger Current, Current Required to Latch Output (Main Terminal Voltage = 3 V(3)) MOC3010 MOC3011 MOC3012	lFT	_ _ _	8 5 3	15 10 5	mA
Holding Current, Either Direction	lн	_	100	_	μА

- 1. Test voltage must be applied within dv/dt rating.
- 2. This is static dv/dt. See Figure 7 for test circuit. Commutating dv/dt is a function of the load–driving thyristor(s) only.
- 3. All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Therefore, recommended operating I_F lies between max I_{FT} (15 mA for MOC3010, 10 mA for MOC3011, 5 mA for MOC3012) and absolute max I_F (60 mA).

TYPICAL ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$



+800 +400 -800 -3 -2 -1 0 1 2 3 V_{TM}, ON-STATE VOLTAGE (VOLTS)

Figure 1. LED Forward Voltage versus Forward Current

Figure 2. On-State Characteristics